



## PATENT APPLICATION

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q66212

KIYOKU, HIROYUKI, et al.

Application No.: 09/986,332

Group Art Unit: 1765

Confirmation No.: 5542

Examiner: Anderson, Matthew A.

Filed: November 08, 2001

For:

NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR

SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE

## EXCESS CLAIM FEE PAYMENT LETTER

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

An Amendment Under 37 C.F.R. § 1.111 is attached hereto for concurrent filing in the aboveidentified application. The resulting excess claim fee has been calculated as shown below:

	After Amendment	Highest No. Previously Paid For						
All Claims	27 -	- 46	=	0	X	\$18.00	=	\$0.00
Independent	5 .	- 4	=	1	$\mathbf{x}$	\$84.00	=	\$84.00
<del>-</del>			_	TOT	AL			\$84.00

A check for the statutory fee of \$84.00 is attached. The USPTO is directed and authorized to charge all required fees, except for the Issue Fee and the Publication Fee, to Deposit Account No. 19-4880. Please also credit any overpayments to said Deposit Account. A duplicate copy of this letter is enclosed.

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WASHINGTON OFFICE

PATENT TRADEMARK OFFICE Date: June 18, 2003

Respectfully submitted,

David A. Klein

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